



I'm not robot



I am not robot!

Bulk Through Hole NPN Single Bipolar (BJT) Transistor @ 2mA 5V mA mW MHz. Small Signal Bipolar Transistor, A I (C), V V (BR)CEO, Element, NPN, Silicon, TO 18 Motorola Small-Signal Transistors, FETs and Diodes Device Data Amplifier Transistors NPN Silicon MAXIMUM RATINGS Rating Symbol BCBC Datasheet search, datasheets, Datasheet search site for Electronic Components and Semiconductors, integrated circuits, diodes, triacs and other semiconductors Download BCB datasheet from ON Semiconductor: pdf kb: NPN Silicon Transistor for AF pre and driver stages Others with the same file for datasheet: BCVI, BCVI, BCVI: Download BCB datasheet from Siemens: pdf kb V, mA, NPN silicon transistor: Download BCB datasheet from Siemens: pdf kb: Discrete Devices Low-Noise: BC, BC Complement to BC, BCB Datasheet. Description: NPN General Purpose Transistor Results. Manufacturer: Weitron Technology. Features. Datasheet: BCB Datasheet (PDF) ECAD Model: Download the free Library Loader to convert BCB – Bipolar (BJT) Transistor NPN V mA MHz mW Through Hole TO from Fairchild Semiconductor. onsemi BCB technical specifications, attributes, and parameters. Datasheet: Kb/9P Amplifier Transistors NPN Silicon Features Pb-Free Packages are Available* MAXIMUM RATINGS Rating Symbol Value Unit Collector Emitter Voltage BC BC BC VCEOVdc Collector Base Voltage BC BC BC VCBOVdc Emitter Base Voltage VEBO Vdc Collector Current – Continuous IC mA Dc Total Device CB Datasheet, PDF: Search Partnumber: Included a word "CB"-Total NPN Epitaxial Silicon Transistor BCBTA Kb 6P: Switching and Amplifier BCBU Collector Base Voltage VCBO Vdc. BCBCBC Emitter Base Voltage VEBO Vdc. Collector Current – Continuous IC mA Dc. Total Device Dissipation @ TC = °C PD Derate above °C Technical Specifications. Part: BCB. Datasheet: Kb/6P. Part: BCB-BP. Datasheet The company was founded in and is headquartered in Phoenix, Arizona. Total Device Dissipation @ TA = °C PD mW Derate above °C mW/ °C. The company's products are designed to be energy efficient, reliable, and cost-effective CB Datasheet. Manufacturer: Micro Technical Specifications. CB Datasheet. The device is housed in the TO package, which is designed for medium power Description: Bipolar Transistors BJT mA V NPN. Lifecycle: Obsolete. onsemi BCB technical specifications, attributes, and parameters. Bulk Through Hole NPN Single Bipolar (BJT) Transistor @ 2mA 5V The NPN Bipolar Transistor is designed for use in linear and switching applications. Part: BCB. Datasheet Mb Kb/5P. Description: Amplifier Transistors (NPN Silicon) Results. High-Voltage: BC, VCEO = V. Datasheet: Kb/5P. Manufacturer: ON Semiconductor. Part: BCB-AP Description: NPN Silicon Amplifier Transistor mW Results. ON Semiconductor offers a broad portfolio of power management, analog, and discrete semiconductors, including power MOSFETs, diodes, rectifiers, and voltage regulators, among others. Pricing and Availability on millions of electronic BC, B BC, A, B, C BC, A, B, C5 Motorola Small-Signal Transistors, FETs and Diodes Device Data PACKAGE DIMENSIONS NOTES DIMENSIONING AND , · NPN Epitaxial Silicon Transistor. Switching and Amplifier.